



Welcome to [E-XFL.COM](https://www.e-xfl.com)

Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Obsolete
Number of LABs/CLBs	2566
Number of Logic Elements/Cells	25660
Total RAM Bits	1944576
Number of I/O	607
Number of Gates	-
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	1020-BBGA
Supplier Device Package	1020-FBGA (33x33)
Purchase URL	https://www.e-xfl.com/product-detail/intel/ep1sgx25ff1020i6

- Pattern detector and word aligner supports programmable patterns
 - 8B/10B encoder/decoder performs 8- to 10-bit encoding and 10- to 8-bit decoding
 - Rate matcher compliant with IEEE 802.3-2002 for GigE mode and with IEEE 802.3ae for XAUI mode
 - Channel bonding compliant with IEEE 802.3ae (for XAUI mode only)
 - Device can bypass some transceiver block features if necessary
- FPGA features are as follows:
- 10,570 to 41,250 logic elements (LEs); see [Table 1–1](#)
 - Up to 3,423,744 RAM bits (427,968 bytes) available without reducing logic resources
 - TriMatrix™ memory consisting of three RAM block sizes to implement true dual-port memory and first-in-out (FIFO) buffers
 - Up to 16 global clock networks with up to 22 regional clock networks per device region
 - High-speed DSP blocks provide dedicated implementation of multipliers (faster than 300 MHz), multiply-accumulate functions, and finite impulse response (FIR) filters
 - Up to eight general usage phase-locked loops (four enhanced PLLs and four fast PLLs) per device provide spread spectrum, programmable bandwidth, clock switchover, real-time PLL reconfiguration, and advanced multiplication and phase shifting
 - Support for numerous single-ended and differential I/O standards
 - High-speed source-synchronous differential I/O support on up to 45 channels for 1-Gbps performance
 - Support for source-synchronous bus standards, including 10-Gigabit Ethernet XSBI, Parallel RapidIO, UTOPIA IV, Network Packet Streaming Interface (NPSI), HyperTransport™ technology, SPI-4 Phase 2 (POS-PHY Level 4), and SFI-4
 - Support for high-speed external memory, including zero bus turnaround (ZBT) SRAM, quad data rate (QDR and QDRII) SRAM, double data rate (DDR) SDRAM, DDR fast cycle RAM (FCRAM), and single data rate (SDR) SDRAM
 - Support for multiple intellectual property megafunctions from Altera® MegaCore® functions and Altera Megafunction Partners Program (AMPPSM) megafunctions
 - Support for remote configuration updates
 - Dynamic phase alignment on LVDS receiver channels

Table 1–1. Stratix GX Device Features

Feature	EP1SGX10C EP1SGX10D	EP1SGX25C EP1SGX25D EP1SGX25F	EP1SGX40D EP1SGX40G
LEs	10,570	25,660	41,250
Transceiver channels	4, 8	4, 8, 16	8, 20
Source-synchronous channels	22	39	45
M512 RAM blocks (32 × 18 bits)	94	224	384
M4K RAM blocks (128 × 36 bits)	60	138	183
M-RAM blocks (4K × 144 bits)	1	2	4
Total RAM bits	920,448	1,944,576	3,423,744
Digital signal processing (DSP) blocks	6	10	14
Embedded multipliers (1)	48	80	112
PLLs	4	4	8

Note to Table 1–1:

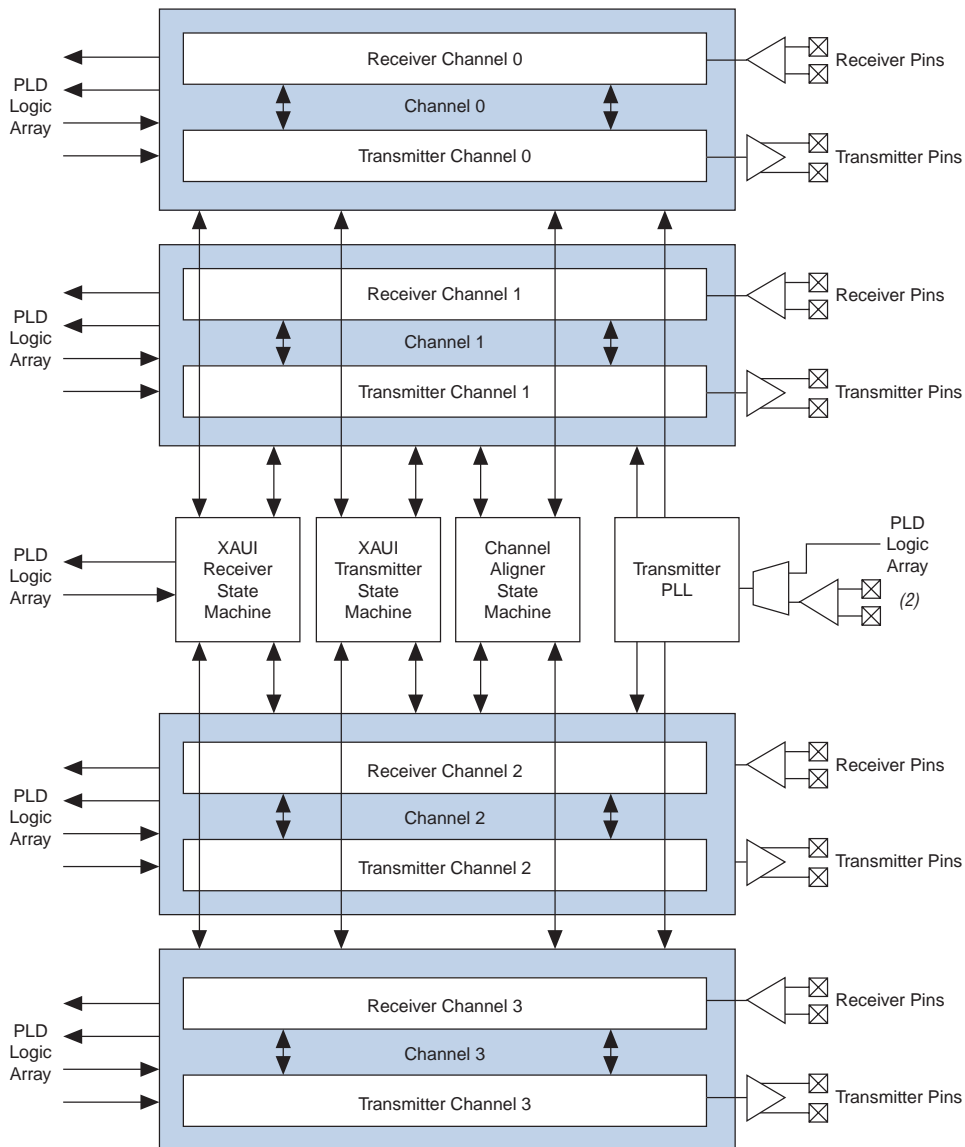
- (1) This parameter lists the total number of 9- × 9-bit multipliers for each device. For the total number of 18- × 18-bit multipliers per device, divide the total number of 9- × 9-bit multipliers by 2. For the total number of 36- × 36-bit multipliers per device, divide the total number of 9- × 9-bit multipliers by 8.

Stratix GX devices are available in space-saving FineLine BGA® packages (refer to Tables 1–2 and 1–3), and in multiple speed grades (refer to Table 1–4). Stratix GX devices support vertical migration within the same package (that is, you can migrate between the EP1SGX10C and EP1SGX25C devices in the 672-pin FineLine BGA package). See the Stratix GX device pin tables for more information. Vertical migration means that you can migrate to devices whose dedicated pins, configuration pins, and power pins are the same for a given package across device densities. For I/O pin migration across densities, you must cross-reference the available I/O pins using the device pin-outs for all planned densities of a given package type, to identify which I/O pins it is possible to migrate. The Quartus II software can automatically cross reference and place all pins for migration when given a device migration list.

Table 1–2. Stratix GX Package Options & I/O Pin Counts (Part 1 of 2) *Note (1)*

Device	672-Pin FineLine BGA	1,020-Pin FineLine BGA
EP1SGX10C	362	
EP1SGX10D	362	
EP1SGX25C	455	

Figure 2–1. Stratix GX Transceiver Block *Note (1)*



Notes to Figure 2–1:

- (1) Each receiver channel has its own PLL and CRU, which are not shown in this diagram. For more information, refer to the section “Receiver Path” on page 2–13.
- (2) For possible transmitter PLL clock inputs, refer to the section “Transmitter Path” on page 2–5.

XAUI Mode

The transmit state machine translates the XAUI XGMII code group to the XAUI PCS code group. Table 2–3 shows the code conversion.

Table 2–3. Code Conversion			
XGMII TXC	XGMII TXD	PCS Code-Group	Description
0	00 through FF	Dxx.y	Normal data
1	07	K28.0 or K28.3 or K28.5	Idle in I
1	07	K28.5	Idle in T
1	9C	K28.4	Sequence
1	FB	K27.7	Start
1	FD	K29.7	Terminate
1	FE	K30.7	Error
1	See IEEE 802.3 reserved code groups	See IEEE 802.3 reserved code groups	Reserved code groups
1	Other value	K30.7	Invalid XGMII character

The XAUI PCS idle code groups, /K28.0/ (/R/) and /K28.5/ (/K/), are automatically randomized based on a PRBS7 pattern with an x^7+x^6+1 polynomial. The /K28.3/ (/A/) code group is automatically generated between 16 and 31 idle code groups. The idle randomization on the /A/, /K/, and /R/ code groups are done automatically by the transmit state machine.

Serializer (Parallel-to-Serial Converter)

The serializer converts the parallel 8-bit or 10-bit data into a serial stream, transmitting the LSB first. The serialized stream is then fed to the transmit buffer. Figure 2–5 is a diagram of the serializer.

Figure 2–23. Data Path in Reverse Serial Loopback Mode

— Active Path
— Non-Active Path

BIST (Built-In Self Test)

The Stratix GX transceiver has built-in self test modes to aid in debug and testing. The BIST modes are set in the Stratix GX MegaWizard Plug-In Manager in the Quartus II software. Only one BIST mode can be set for any single instance of the transceiver block. The BIST mode applies to all channels used in a transceiver.

The following is a list of the available BIST modes:

- PRBS generator and verifier
- Incremental mode generator and verifier
- High-frequency generator
- Low-frequency generator
- Mixed-frequency generator

Figures 2-24 and 2-25 are diagrams of the BIST PRBS data path and the BIST incremental data path, respectively.

Introduction

Expansion in the telecommunications market and growth in Internet use requires systems to move more data faster than ever. To meet this demand, rely on solutions such as differential signaling and emerging high-speed interface standards including RapidIO, POS-PHY 4, SFI-4, or XSBI.

These new protocols support differential data rates up to 1 Gbps and higher. At these high data rates, it becomes more challenging to manage the skew between the clock and data signals. One solution to this challenge is to use CDR to eliminate skew between data channels and clock signals. Another potential solution, DPA, is beginning to be incorporated into some of these protocols.

The source-synchronous high-speed interface in Stratix GX devices is a dedicated circuit embedded into the PLD allowing for high-speed communications. The *High-Speed Source-Synchronous Differential I/O Interfaces in Stratix GX Devices* chapter of the *Stratix GX Device Handbook, Volume 2* provides information on the high-speed I/O standard features and functions of the Stratix GX device.

Stratix GX I/O Banks

Stratix GX devices contain 17 I/O banks. I/O banks one and two support high-speed LVDS, LVPECL, and 3.3-V PCML inputs and outputs. These two banks also incorporate an embedded dynamic phase aligner within the source-synchronous interface (see [Figure 3-8 on page 3-10](#)). The dynamic phase aligner corrects for the phase difference between the clock and data lines caused by skew. The dynamic phase aligner operates automatically and continuously without requiring a fixed training pattern, and allows the source-synchronous circuitry to capture data correctly regardless of the channel-to-clock skew.

Principles of SERDES Operation

Stratix GX devices support source-synchronous differential signaling up to 1 Gbps in DPA mode, and up to 840 Mbps in non-DPA mode. Serial data is transmitted and received along with a low-frequency clock. The PLL can multiply the incoming low-frequency clock by a factor of 1 to 10. The SERDES factor J can be 8 or 10 for the DPA mode, or 4, 7, 8, or 10 for all other modes. The SERDES factor does not have to equal the clock

Figure 3–10. Misaligned Captured Bits**Correct Alignment**

0	1	2	3	4	5	6	7
---	---	---	---	---	---	---	---

Incorrect Alignment

3	4	5	6	7	0	1	2
---	---	---	---	---	---	---	---

The dynamic phase selector and synchronizer align the clock and data based on the power-up of both communicating devices, and the channel to channel skew. However, the dynamic phase selector and synchronizer cannot determine the byte boundary, and the data may need to be byte-aligned. The dynamic phase aligner's data realignment circuitry shifts data bits to correct bit misalignments.

The Stratix GX circuitry contains a data-realignment feature controlled by the logic array. Stratix GX devices perform data realignment on the parallel data after the deserialization block. The data realignment can be performed per channel for more flexibility. The data alignment operation requires a state machine to recognize a specific pattern. The procedure requires the bits to be slipped on the data stream to correctly align the incoming data to the start of the byte boundary.

The DPA uses its realignment circuitry and the global clock for data realignment. Either a device pin or the logic array asserts the internal `rx_channel_data_align` node to activate the DPA data-realignment circuitry. Switching this node from low to high activates the realignment circuitry and the data being transferred to the logic array is shifted by one bit. The data realignment block cannot be bypassed. However, if the `rx_channel_data_align` is not turned on (through the `altvlds` MegaWizard Plug-In Manager), or when it is not toggled, it only acts as a register latency.

A state machine and additional logic can monitor the incoming parallel data and compare it against a known pattern. If the incoming data pattern does not match the known pattern, you can activate the `rx_channel_data_align` node again. Repeat this process until the realigner detects the desired match between the known data pattern and incoming parallel data pattern.

Table 4–2. TriMatrix Memory Features (Part 2 of 2)

Memory Feature	M512 RAM Block (32 × 18 Bits)	M4K RAM Block (128 × 36 Bits)	M-RAM Block (4K × 144 Bits)
Configurations	512 × 1 256 × 2 128 × 4 64 × 8 64 × 9 32 × 16 32 × 18	4K × 1 2K × 2 1K × 4 512 × 8 512 × 9 256 × 16 256 × 18 128 × 32 128 × 36	64K × 8 64K × 9 32K × 16 32K × 18 16K × 32 16K × 36 8K × 64 8K × 72 4K × 128 4K × 144

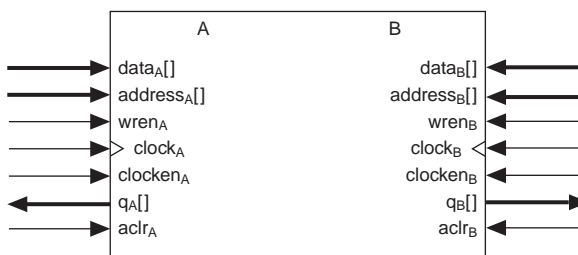
Notes to Table 4–2:

- (1) See the *DC & Switching Characteristics* chapter of the *Stratix GX Device Handbook, Volume 1* for maximum performance information.
- (2) The M-RAM block does not support memory initializations. However, the M-RAM block can emulate a ROM function using a dual-port RAM block. The Stratix GX device must write to the dual-port memory once and then disable the write-enable ports afterwards.

Memory Modes

TriMatrix memory blocks include input registers that synchronize writes and output registers to pipeline designs and improve system performance. M4K and M-RAM memory blocks offer a true dual-port mode to support any combination of two-port operations: two reads, two writes, or one read and one write at two different clock frequencies.

Figure 4–11 shows true dual-port memory.

Figure 4–11. True Dual-Port Memory Configuration

In addition to true dual-port memory, the memory blocks support simple dual-port and single-port RAM. Simple dual-port memory supports a simultaneous read and write and can either read old data before the write

The memory address depths and output widths can be configured as $4,096 \times 1$, $2,048 \times 2$, $1,024 \times 4$, 512×8 (or 512×9 bits), 256×16 (or 256×18 bits), and 128×32 (or 128×36 bits). The 128×32 - or 36 -bit configuration is not available in the true dual-port mode. Mixed-width configurations are also possible, allowing different read and write widths. Tables 4-4 and 4-5 summarize the possible M4K RAM block configurations.

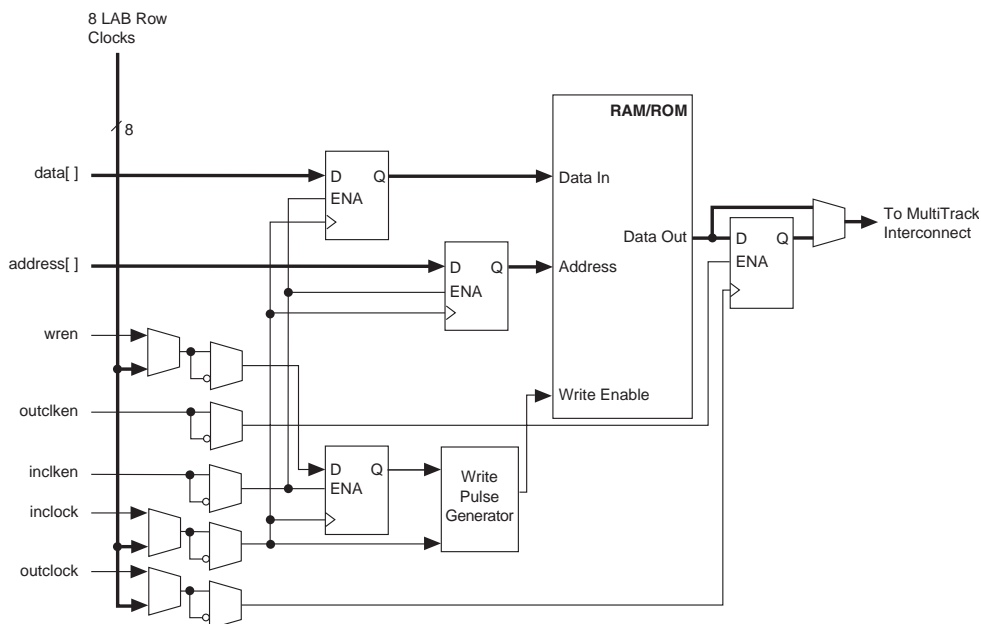
Table 4-4. M4K RAM Block Configurations (Simple Dual-Port)

Read Port	Write Port								
	4K × 1	2K × 2	1K × 4	512 × 8	256 × 16	128 × 32	512 × 9	256 × 18	128 × 36
4K × 1	✓	✓	✓	✓	✓	✓			
2K × 2	✓	✓	✓	✓	✓	✓			
1K × 4	✓	✓	✓	✓	✓	✓			
512 × 8	✓	✓	✓	✓	✓	✓			
256 × 16	✓	✓	✓	✓	✓	✓			
128 × 32	✓	✓	✓	✓	✓	✓			
512 × 9							✓	✓	✓
256 × 18							✓	✓	✓
128 × 36							✓	✓	✓

Table 4-5. M4K RAM Block Configurations (True Dual-Port)

Port A	Port B						
	4K × 1	2K × 2	1K × 4	512 × 8	256 × 16	512 × 9	256 × 18
4K × 1	✓	✓	✓	✓	✓		
2K × 2	✓	✓	✓	✓	✓		
1K × 4	✓	✓	✓	✓	✓		
512 × 8	✓	✓	✓	✓	✓		
256 × 16	✓	✓	✓	✓	✓		
512 × 9						✓	✓
256 × 18						✓	✓

When the M4K RAM block is configured as a shift register block, you can create a shift register up to 4,608 bits ($w \times m \times n$).

Figure 4–27. Single-Port Mode

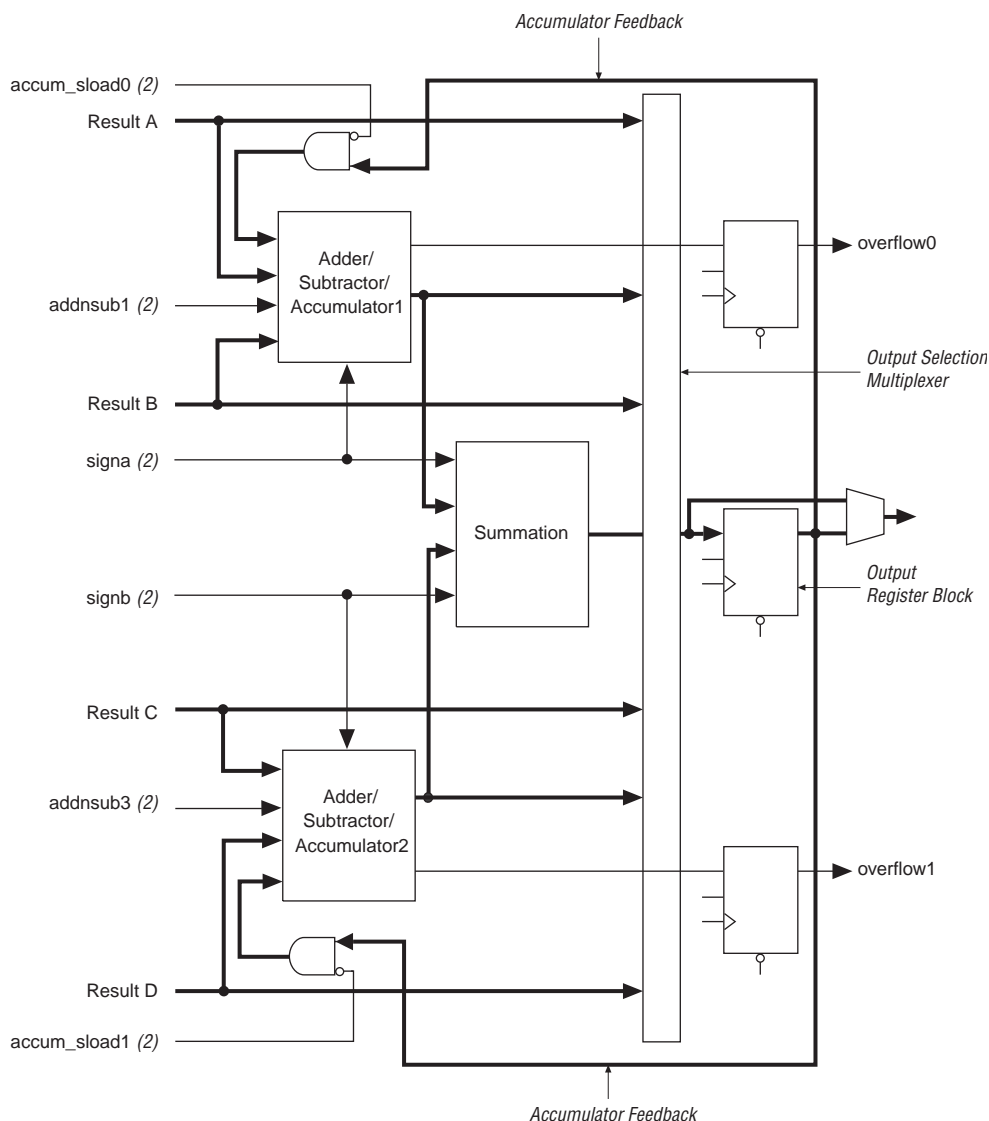
Digital Signal Processing Block

The most commonly used DSP functions are finite impulse response (FIR) filters, complex FIR filters, infinite impulse response (IIR) filters, fast Fourier transform (FFT) functions, direct cosine transform (DCT) functions, and correlators. All of these blocks have the same fundamental building block: the multiplier. Additionally, some applications need specialized operations such as multiply-add and multiply-accumulate operations. Stratix GX devices provide DSP blocks to meet the arithmetic requirements of these functions.

Each Stratix GX device has two columns of DSP blocks to efficiently implement DSP functions faster than LE-based implementations. Larger Stratix GX devices have more DSP blocks per column (see [Table 4–12](#)). Each DSP block can be configured to support up to:

- Eight 9×9 -bit multipliers
- Four 18×18 -bit multipliers
- One 36×36 -bit multiplier

As indicated, the Stratix GX DSP block can support one 36×36 -bit multiplier in a single DSP block. This is true for any matched sign multiplications (either unsigned by unsigned or signed by signed), but

Figure 4–33. Adder/Output Blocks *Note (1)***Notes to Figure 4–33:**

- (1) Adder/output block shown in Figure 4–33 is in 18×18 -bit mode. In 9×9 -bit mode, there are four adder/subtractor blocks and two summation blocks.
- (2) These signals are either not registered, registered once, or registered twice to match the data path pipeline.

Figure 4–43. EP1SGX25 & EP1SGX10 Device Fast Clock Pin Connections to Fast Regional Clocks

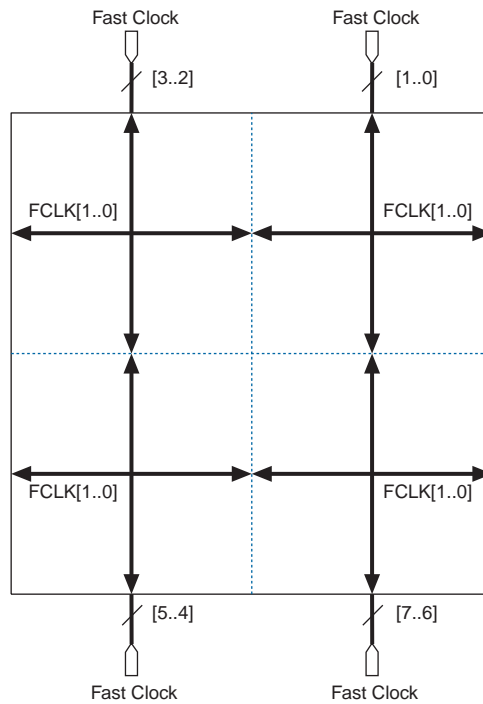


Table 4–27. Stratix GX Supported I/O Standards (Part 2 of 2)

I/O Standard	Type	Input Reference Voltage (V_{REF}) (V)	Output Supply Voltage (V_{CCIO}) (V)	Board Termination Voltage (V_{TT}) (V)
SSTL-3 class I and II	Voltage-referenced	1.5	3.3	1.5
AGP (1× and 2×)	Voltage-referenced	1.32	3.3	N/A
CTT	Voltage-referenced	1.5	3.3	1.5

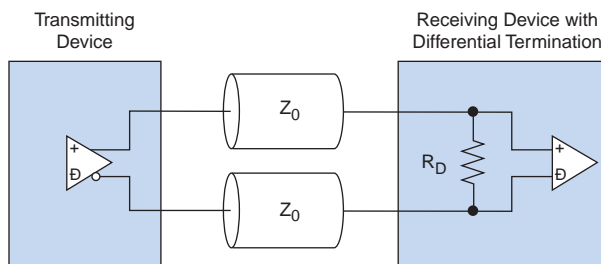
Notes to Table 4–27:

- (1) This I/O standard is only available on input and output clock pins.
- (2) This I/O standard is only available on output column clock pins.



For more information on I/O standards supported by Stratix GX devices, see the *Selectable I/O Standards in Stratix & Stratix GX Devices* chapter of the *Stratix GX Device Handbook, Volume 2*.

Stratix GX devices contain eight I/O banks in addition to the four enhanced PLL external clock out banks, as shown in [Figure 4–69](#). The four I/O banks on the right and left of the device contain circuitry to support high-speed differential I/O for LVDS, LVPECL, 3.3-V PCML, and HyperTransport inputs and outputs. These banks support all I/O standards listed in [Table 4–27](#) except PCI I/O pins or PCI-X 1.0, GTL, SSTL-18 Class II, and HSTL Class II outputs. The top and bottom I/O banks support all single-ended I/O standards. Additionally, Stratix GX devices support four enhanced PLL external clock output banks, allowing clock output capabilities such as differential support for SSTL and HSTL. [Table 4–28](#) shows I/O standard support for each I/O bank.

Figure 4–70. LVDS Input Differential On-Chip Termination

I/O banks on the left and right side of the device support LVDS receiver (far-end) differential termination.

Table 4–29 shows the Stratix GX device differential termination support.

Table 4–29. Differential Termination Supported by I/O Banks

Differential Termination Support	I/O Standard Support	Top & Bottom Banks (3, 4, 7 & 8)	Left Banks (1 & 2)
Differential termination (1), (2)	LVDS		✓

Notes to Table 4–29:

- (1) Clock pin CLK0, CLK2, CLK9, CLK11, and pins FPLL [7..10] CLK do not support differential termination.
- (2) Differential termination is only supported for LVDS because of a 3.3-V V_{CCIO} .

Table 4–30 shows the termination support for different pin types.

Table 4–30. Differential Termination Support Across Pin Types

Pin Type	R_D
Top and bottom I/O banks (3, 4, 7, and 8)	
DIFFIO_RX []	✓
CLK [0, 2, 9, 11], CLK [4–7], CLK [12–15]	
CLK [1, 3, 8, 10]	✓
FCLK	
FPLL [7..10] CLK	

The differential on-chip resistance at the receiver input buffer is $118\ \Omega \pm 20\%$.

Table 6–7. Stratix GX Transceiver Block AC Specification (Part 6 of 7)

Symbol / Description	Conditions	-5 Commercial Speed Grade (1)			-6 Commercial & Industrial Speed Grade (1)			-7 Commercial & Industrial Speed Grade (1)			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
XAUI Transmitter Jitter using 8B/10B Encoded CJPAT Note (9)											
Deterministic jitter	3.125 Gbps Pre-emphasis = 0 V _{OD} = 1,200 mV			0.15			0.15			N/A	UI
Total jitter				0.32			0.32			N/A	UI
Jitter transfer bandwidth (10)	Low bandwidth setting at 3.125 Gbps		3			3				N/A	MHz
	High bandwidth setting at 3.125 Gbps		4.7			4.7				N/A	MHz
	Low bandwidth setting at 2.5 Gbps		3.2			3.2				3.2	MHz
	High bandwidth setting at 2.5 Gbps		4.3			4.3				4.3	MHz
Output t _{RISE}	20% to 80%	60		130	60		130	60		130	ps
Output t _{FALL}	80% to 20%	60		130	60		130	60		130	ps
Transmit latency (11)	Single width	3		8	3		8	3		8	(3)
	Double width	3		7	3		7	3		7	(3)
Intra differential pair skew				10			10			10	ps
Channel to channel skew	Within a single quadrant			50			50			50	ps

Table 6–26. SSTL-3 Class II Specifications (Part 2 of 2)

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Units
V_{IL}	Low-level input voltage		–0.3		$V_{REF} - 0.2$	V
V_{OH}	High-level output voltage	$I_{OH} = -16 \text{ mA}$ (1)	$V_{TT} + 0.8$			V
V_{OL}	Low-level output voltage	$I_{OL} = 16 \text{ mA}$ (1)			$V_{TT} - 0.8$	V

Table 6–27. 3.3-V AGP 2× Specifications

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Units
V_{CCIO}	Output supply voltage		3.15	3.3	3.45	V
V_{REF}	Reference voltage		$0.39 \times V_{CCIO}$		$0.41 \times V_{CCIO}$	V
V_{IH}	High-level input voltage (2)		$0.5 \times V_{CCIO}$		$V_{CCIO} + 0.5$	V
V_{IL}	Low-level input voltage (2)				$0.3 \times V_{CCIO}$	V
V_{OH}	High-level output voltage	$I_{OUT} = -0.5 \text{ mA}$	$0.9 \times V_{CCIO}$		3.6	V
V_{OL}	Low-level output voltage	$I_{OUT} = 1.5 \text{ mA}$			$0.1 \times V_{CCIO}$	V

Table 6–28. 3.3-V AGP 1× Specifications

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Units
V_{CCIO}	Output supply voltage		3.15	3.3	3.45	V
V_{IH}	High-level input voltage (2)		$0.5 \times V_{CCIO}$		$V_{CCIO} + 0.5$	V
V_{IL}	Low-level input voltage (2)				$0.3 \times V_{CCIO}$	V
V_{OH}	High-level output voltage	$I_{OUT} = -0.5 \text{ mA}$	$0.9 \times V_{CCIO}$		3.6	V
V_{OL}	Low-level output voltage	$I_{OUT} = 1.5 \text{ mA}$			$0.1 \times V_{CCIO}$	V

Table 6–29. 1.5-V HSTL Class I Specifications (Part 1 of 2)

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Units
V_{CCIO}	Output supply voltage		1.4	1.5	1.6	V
V_{REF}	Input reference voltage		0.68	0.75	0.9	V
V_{TT}	Termination voltage		0.7	0.75	0.8	V
$V_{IH}(\text{DC})$	DC high-level input voltage		$V_{REF} + 0.1$			V
$V_{IL}(\text{DC})$	DC low-level input voltage		–0.3		$V_{REF} - 0.1$	V
$V_{IH}(\text{AC})$	AC high-level input voltage		$V_{REF} + 0.2$			V
$V_{IL}(\text{AC})$	AC low-level input voltage				$V_{REF} - 0.2$	V

Table 6–48. M4K Block Internal Timing Microparameters (Part 2 of 2)

Symbol	-5 Speed Grade		-6 Speed Grade		-7 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
$t_{M4KDATAO1}$		571		635		729	ps
$t_{M4KDATAO2}$		3,984		4,507		5,182	ps
$t_{M4KCLKHL}$	150		167		192		ps
t_{M4KCLR}	170		189		255		ps

Table 6–49. M-RAM Block Internal Timing Microparameters

Symbol	-5		-6		-7		Unit
	Min	Max	Min	Max	Min	Max	
t_{MRAMRC}		4,364		4,838		5,562	ps
t_{MRAMWC}		3,654		4,127		4,746	ps
$t_{MRAMWERESU}$	25		25		28		ps
$t_{MRAMWERH}$	18		20		23		ps
$t_{MRAMDATASU}$	25		25		28		ps
$t_{MRAMDATAH}$	18		20		23		ps
$t_{MRAMWADDRASU}$	25		25		28		ps
$t_{MRAMWADDRH}$	18		20		23		ps
$t_{MRAMRADDRASU}$	25		25		28		ps
$t_{MRAMRADDRH}$	18		20		23		ps
$t_{MRAMDATABSU}$	25		25		28		ps
$t_{MRAMDATABH}$	18		20		23		ps
$t_{MRAMADDRBSU}$	25		25		28		ps
$t_{MRAMADDRBH}$	18		20		23		ps
$t_{MRAMDATAO1}$		1,038		1,053		1,210	ps
$t_{MRAMDATAO2}$		4,362		4,939		5,678	ps
$t_{MRAMCLKHL}$	270		300		345		ps
$t_{MRAMCLR}$	135		150		172		ps

Table 6–74. Stratix GX I/O Standard Output Delay Adders for Fast Slew Rate on Column Pins (Part 2 of 2)

Standard	-5 Speed Grade		-6 Speed Grade		-7 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
GTL+		–110		–115		–133	ps
3.3-V PCI		–230		–241		–277	ps
3.3-V PCI-X 1.0		–230		–241		–277	ps
Compact PCI		–230		–241		–277	ps
AGP 1×		–30		–31		–36	ps
AGP 2×		–30		–31		–36	ps
CTT		50		53		61	ps
SSTL-3 class I		90		95		109	ps
SSTL-3 class II		–50		–52		–60	ps
SSTL-2 class I		100		105		120	ps
SSTL-2 class II		20		21		24	ps
SSTL-18 class I		230		242		278	ps
SSTL-18 class II		0		0		0	ps
1.5-V HSTL class I		380		399		459	ps
1.5-V HSTL class II		190		200		230	ps
1.8-V HSTL class I		380		399		459	ps
1.8-V HSTL class II		390		410		471	ps

Table 6–75. Stratix GX I/O Standard Output Delay Adders for Fast Slew Rate on Row Pins (Part 1 of 2)

Standard		-5 Speed Grade		-6 Speed Grade		-7 Speed Grade		Unit
		Min	Max	Min	Max	Min	Max	
LVCMOS	2 mA		570		599		689	ps
	4 mA		570		599		689	ps
	8 mA		350		368		423	ps
	12 mA		130		137		157	ps
	24 mA		0		0		0	ps
3.3-V LVTTL	4 mA		570		599		689	ps
	8 mA		350		368		423	ps
	12 mA		130		137		157	ps
	16 mA		70		74		85	ps
	24 mA		0		0		0	ps

Table 6–91 describes the Stratix GX device fast PLL specifications.

Table 6–91. Fast PLL Specifications for -5 & -6 Speed Grade Devices				
Symbol	Parameter	Min	Max	Unit
f_{IN}	CLKIN frequency (for $m = 1$) (1)	300	717	MHz
	CLKIN frequency (for $m = 2$ to 19)	300/ m	1,000/ m	MHz
	CLKIN frequency (for $m = 20$ to 32)	10	1,000/ m	MHz
f_{OUT}	Output frequency for internal global or regional clock (2)	9.4	420	MHz
f_{OUT_EXT}	Output frequency for external clock	9.375	717	MHz
f_{VCO}	VCO operating frequency	300	1,000	MHz
t_{INDUTY}	CLKIN duty cycle	40	60	%
$t_{INJITTER}$	Period jitter for CLKIN pin		±200	ps
t_{DUTY}	Duty cycle for DIFFIO 1 × CLKOUT pin (3)	45	55	%
t_{JITTER}	Period jitter for DIFFIO clock out (3)		±80	ps
	Period jitter for internal global or regional clock		±100 ps for >200-MHz outclk ±20 mUI for <200-MHz outclk	ps or mUI
t_{LOCK}	Time required for PLL to acquire lock	10	100	μs
m	Multiplication factors for m counter (3)	1	32	Integer
l_0, l_1, g_0	Multiplication factors for l_0, l_1 , and g_0 counter (4), (5)	1	32	Integer
t_{ARESET}	Minimum pulse width on areset signal	10		ns

Table 6–92. Fast PLL Specifications for -7 & -8 Speed Grades (Part 1 of 2)				
Symbol	Parameter	Min	Max	Unit
f_{IN}	CLKIN frequency (for $m = 1$) (1),	300	640	MHz
	CLKIN frequency (for $m = 2$ to 19)	300/ m	700/ m	MHz
	CLKIN frequency (for $m = 20$ to 32)	10	700/ m	MHz
f_{OUT}	Output frequency for internal global or regional clock (2)	9.375	420	MHz
f_{OUT_EXT}	Output frequency for external clock	9.4	500	MHz
f_{VCO}	VCO operating frequency	300	700	MHz
t_{INDUTY}	CLKIN duty cycle	40	60	%
$t_{INJITTER}$	Period jitter for CLKIN pin		±200	ps